Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Plastic

Semiconductor Material:

Gallium arsenide

Voltage Rating In Volts Per Characteristic:

3.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

1.00 amperes forward current, average preset and 50.00 milliamperes source cutoff current preset

Power Rating Per Characteristic:

120.0 milliwatts small-signal input power, common-collector preset

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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